

In the claims:

Please amend claim 5 as follows:

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5. (Amended) An active matrix device comprising:
- a first substrate;
 - a second substrate opposed to said first substrate;
 - a thin film transistor formed over said first substrate, said thin film transistor comprising an active layer;
 - an interlayer insulating film formed over the thin film transistor;
 - at least two source lines formed over said thin film transistor;
 - at least two gate lines intersecting to said two source lines respectively;
 - a metal interconnection connected to said active layer through a first contact hole formed in the interlayer insulating film;
 - a pixel by said two source lines and said two gate lines;
 - a light blocking film formed over said thin film transistor;
 - a capacitor formed between a portion of said metal interconnection and said light blocking film with a second interlayer insulating film interposed therebetween;
 - a pixel electrode formed over said light blocking film;
- and
- liquid crystal molecules arranged between said first substrate and said second substrate, said liquid crystal molecules oriented by rubbing in one direction from one corner of said pixel,
- wherein said portion is apart from the contact hole, and
- wherein a disclination of said liquid crystal molecules is occurred in a region comprising said one corner, and wherein said region and said capacitor overlaps with each other.
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